## NSN 5961-01-071-3250

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-071-3250 **Inclosure Material:** Metal **Overall Length:** Between 1.025 inches and 1.065 inches Overall Diameter: 2.100 inches **End Application:** An/tpq-37 and an/tpq-36 firefinder radar. **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 750.0 nonrepetitive peak reverse voltage, peak total value and 650.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 700.00 amperes forward current, total rms of standard range **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 05869-723097 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: